

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting up to 256 W (8 x 32 W)
- Switch mode power supplies

Description

The device is manufactured using the diffused collector in planar technology adopting new and enhanced high voltage structure. It has an intrinsic ruggedness which enables the transistor to withstand an high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

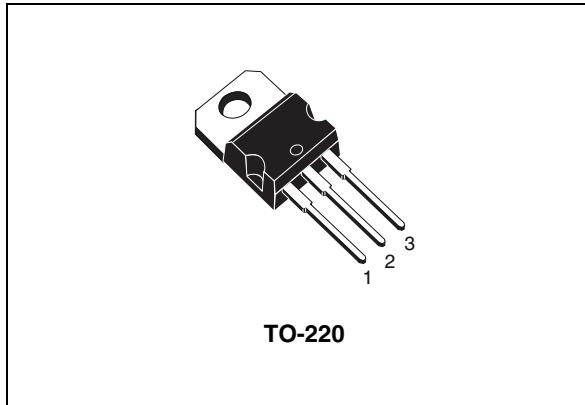


Figure 1. Internal schematic diagram

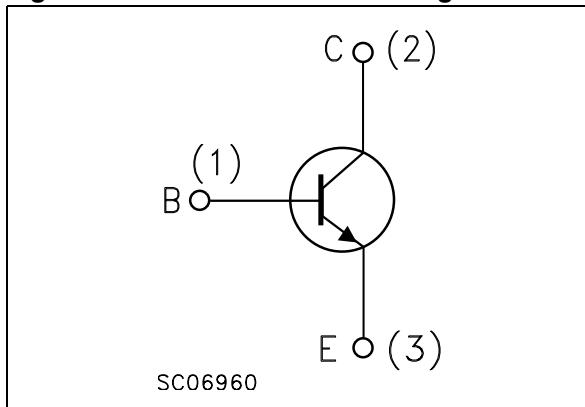


Table 1. Device summary

Order code	Marking	Package	Packaging
BUL743	BUL743	TO-220	Tube

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	1200	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	500	V
V_{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 6$ A, $t_p < 10$ ms)	$V_{(BR)EBO}$	V
I_C	Collector current	12	A
I_{CM}	Collector peak current ($t_p < 5$ ms)	24	A
I_B	Base current	6	A
I_{BM}	Base peak current ($t_p < 5$ ms)	12	A
P_{tot}	Total dissipation at $T_c = 25$ °C	100	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction - case	1.25	°C/W
$R_{thj-amb}$	Thermal resistance junction - ambient	62.5	°C/W

2 Electrical characteristics

($T_{case} = 25^\circ C$ unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{BE} = 0$)	$V_{CE} = 1200 V$		0.2	10	μA
I_{CEO}	Collector cut-off current ($I_B = 0$)	$V_{CE} = 500 V$		10	250	μA
$V_{(BR)EBO}$	Emitter base breakdown voltage ($I_C = 0$)	$I_E = 1 mA$	15	19	24	V
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 50 mA$	500			V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 3 A \quad I_B = 0.6 A$ $I_C = 10 A \quad I_B = 2.5 A$		0.15 0.6	0.5 1.5	V V
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 10 A \quad I_B = 2.5 A$		1.1	1.5	V
$h_{FE}^{(1)}$	DC current gain	$I_C = 0.5 A \quad V_{CE} = 5 V$ $I_C = 2 A \quad V_{CE} = 3 V$	35 24	55 34	80 45	
t_s t_f	Resistive load Storage time Fall time	$I_C = 6 A \quad V_{CC} = 125 V$ $I_{B(on)} = -I_{B(off)} = 1.2 A$ $t_p = 300 \mu s \quad V_{BE(off)} = -5 V$		2.5 400	3.8 500	μs ns
E_{ar}	Repetitive avalanche energy	$L = 2 mH \quad C = 1.8 nF$ $V_{BE(off)} = -5 V$	3			mJ

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

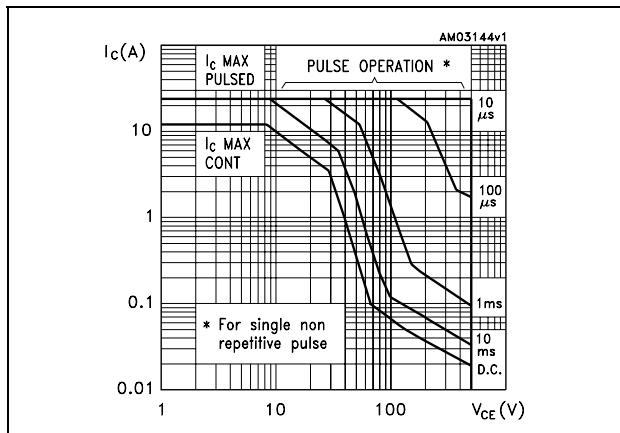


Figure 3. Derating curve

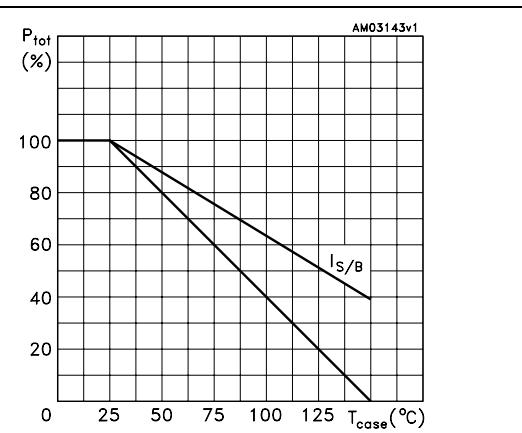


Figure 4. DC current gain ($V_{CE} = 3$ V)

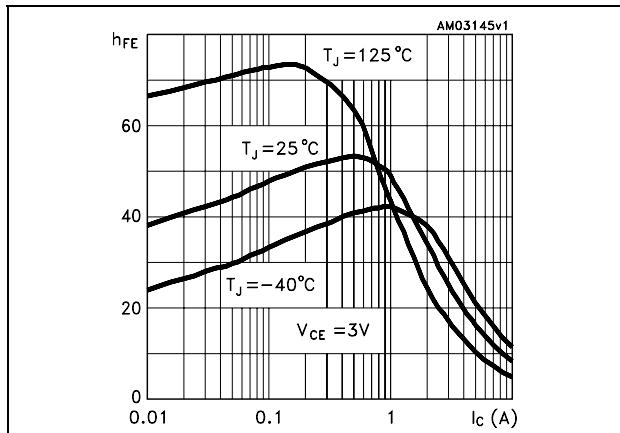


Figure 5. DC current gain ($V_{CE} = 5$ V)

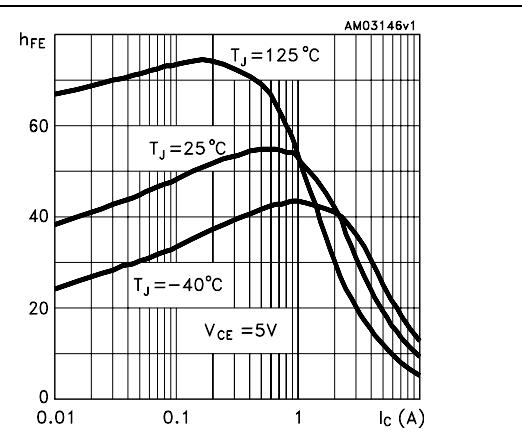


Figure 6. Collector-emitter saturation voltage

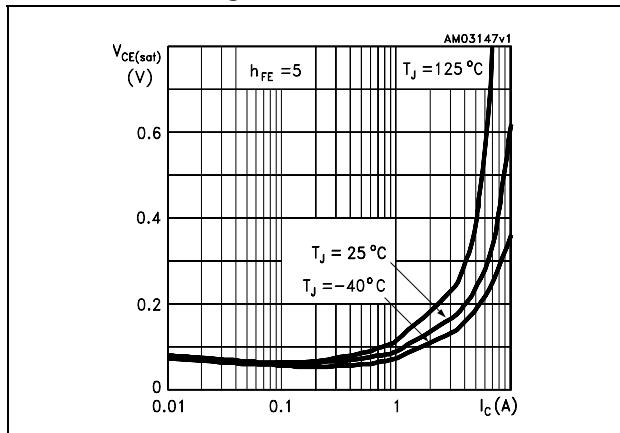


Figure 7. Base-emitter saturation voltage

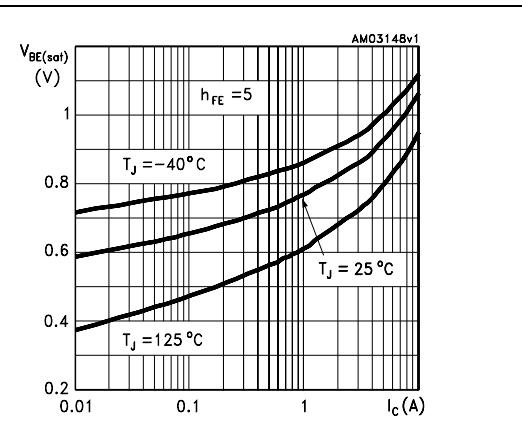
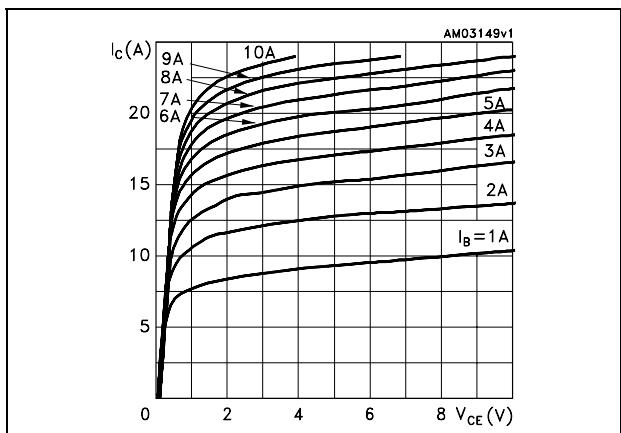
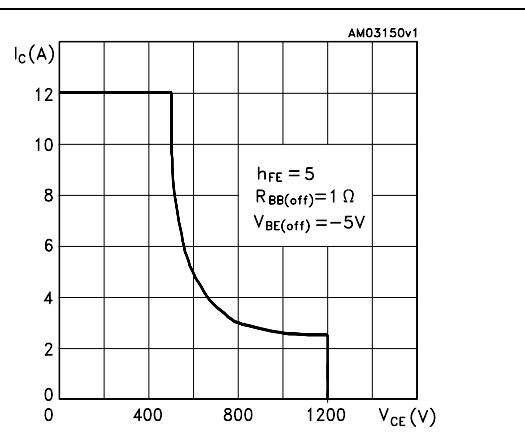
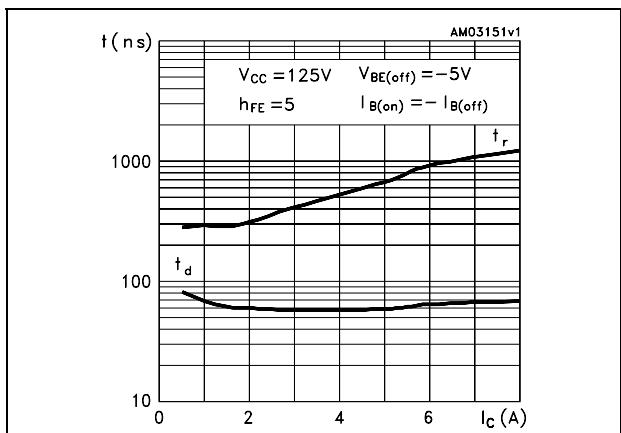
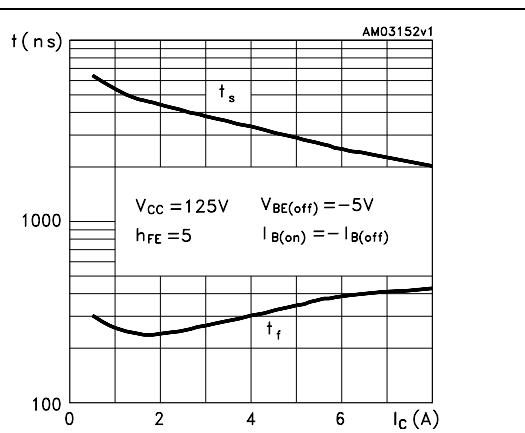


Figure 8. Output characteristics**Figure 9. Reverse biased safe operating area****Figure 10. Resistive load switching time (on)****Figure 11. Resistive load switching time (off)**

2.2 Test circuits

Figure 12. Energy rating test circuit

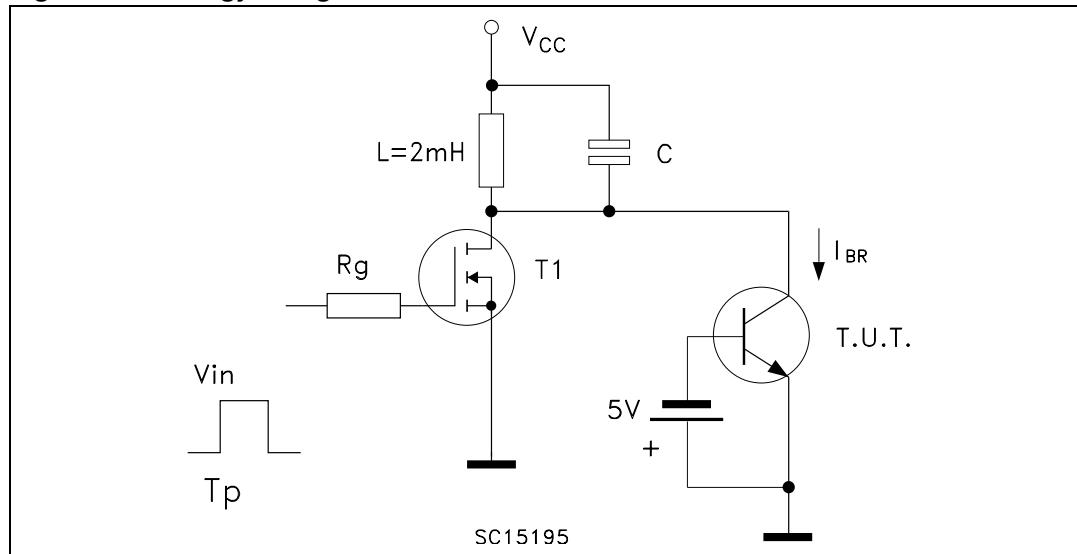
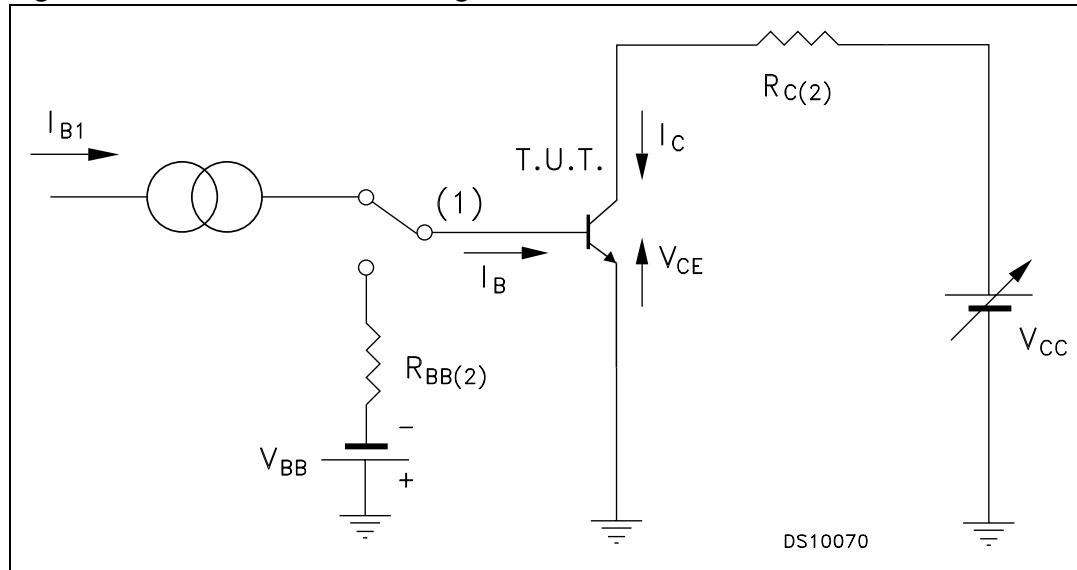


Figure 13. Resistive load switching test circuit



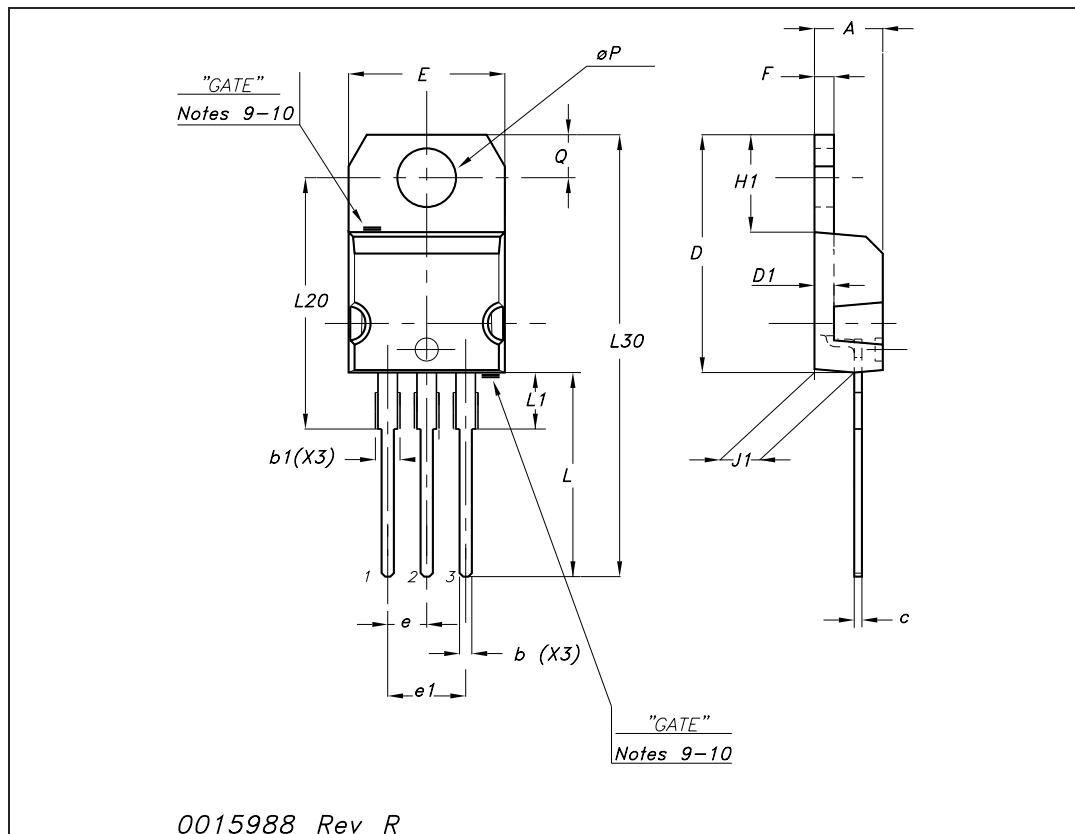
1. Fast electronic switch
2. Non-inductive resistor

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
ECOPACK® is an ST trademark.

TO-220 mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
$\emptyset P$	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



0015988_Rev_R

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
09-Dec-2008	1	First release
20-Mar-2009	2	Added Section 2.1 Section 2.1: Electrical characteristics (curves) on page 4
25-May-2009	3	Document status promoted from preliminary data to datasheet

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